

# TinyLogic UHS Triple Inverter with Schmitt Trigger Input

## NC7NZ14

#### Description

The NC7NZ14 is a triple inverter with Schmitt trigger input from **onsemi**'s Ultra–High Speed (UHS) series of TinyLogic. The device is fabricated with advanced CMOS technology to achieve ultra–high speed with high output drive while maintaining low static power dissipation over a very broad  $V_{CC}$  operating range. The device is specified to operate over the 1.65 V to 5.5 V  $V_{CC}$  range. The inputs and outputs are high–impedance when  $V_{CC}$  is 0 V. Inputs tolerate voltages up to 5.5 V independent of  $V_{CC}$  operating voltage.

#### **Features**

- Ultra High-Speed:  $t_{PD}$  = 3.7 ns (Typical) into 50 pF at 5 V  $V_{CC}$
- High Output Drive: ±24 mA at 3 V V<sub>CC</sub>
- Broad V<sub>CC</sub> Operating Range: 1.65 V to 5.5 V
- Power Down High Impedance Inputs / Outputs
- Over-Voltage Tolerance Inputs Facilitate 5 V to 3 V Translation
- Proprietary Noise / EMI Reduction Circuitry
- Ultra-Small MicroPak<sup>TM</sup> Packages
- Space-Saving US8 Surface Mount Package
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

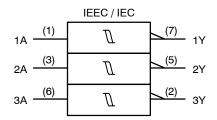


Figure 1. Logic Symbol

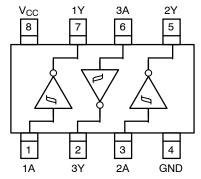


Figure 2. Connection Diagram (Top View)

#### MARKING DIAGRAMS



UQFN8 1.6X1.6, 0.5P CASE 523AY P6KK XYZ



US8 CASE 846AN



P6, NZ14 = Specific Device Code

KK = 2-Digit Lot Run Traceability Code

XY = 2-Digit Date Code Format

Z = Assembly Plant Code

A = Assembly Site

L = Wafer Lot Number

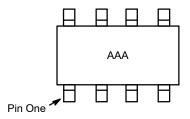
YW = Assembly Start Week

#### **ORDERING INFORMATION**

See detailed ordering, marking and shipping information on page 6 of this data sheet.

NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 6.

## **Pin Configurations**



## NOTES:

- AAA represents product code top mark (see ordering table).
   Orientation of top mark determines pin one location. Reading the top product code mark left to right, pin one is the lower left pin.

Figure 3. US8

## 1A 3Y 2A 4 GND V<sub>CC</sub> 8 зА 2Y

Figure 4. MicroPak (Top Through View)

## **PIN DEFINITIONS**

Pin # US8	Pin # MicroPak	Name	Description
1	7	1A	Input
2	6	3Y	Output
3	5	2A	Input
4	4	GND	Ground
5	3	2Y	Output
6	2	ЗА	Input
7	1	1Y	Output
8	8	V <sub>CC</sub>	Supply Voltage

## **FUNCTION TABLE**

Input	Output
Α	Y
L	Н
Н	L

H = HIGH Logic Level L = LOW Logic Level

#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Paran	Min	Max	Unit	
V <sub>CC</sub>	Supply Voltage		-0.5	6.5	V
V <sub>IN</sub>	DC Input Voltage		-0.5	6.5	V
V <sub>OUT</sub>	DC Output Voltage		-0.5	6.5	V
I <sub>IK</sub>	DC Input Diode Current	V <sub>IN</sub> < 0 V	-	-50	mA
I <sub>OK</sub>	DC Output Diode Current	V <sub>OUT</sub> < 0 V	-	-50	mA
I <sub>OUT</sub>	DC Output Current	-	±50	mA	
I <sub>CC</sub> / I <sub>GND</sub>	DC V <sub>CC</sub> or Ground Current	-	±50	mA	
T <sub>STG</sub>	Storage Temperature Range	-65	+150	°C	
TJ	Junction Temperature Under Bia	s	-	+150	°C
$T_L$	Junction Lead Temperature (Solo	dering, 10 Seconds)	-	+260	°C
$P_{D}$	Power Dissipation in Still Air US8		-	500	mW
		MicroPak-8	-	539	
ESD	Human Body Model, JEDEC: JESD22-A114		-	4000	V
	Charge Device Model, JEDEC: J	ESD22-C101	-	2000	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	Supply Voltage Operating		1.65	5.5	V
	Supply Voltage Data Retention		1.5	5.5	
V <sub>IN</sub>	Input Voltage		0	5.5	V
V <sub>OUT</sub>	Output Voltage		0	V <sub>CC</sub>	V
T <sub>A</sub>	Operating Temperature		-40	+85	°C
$\theta_{JA}$	Thermal Resistance	US8	-	250	°C/W
		MicroPak-8	_	232	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.



<sup>3.</sup> Unused inputs must be held HIGH or LOW. They may not float.

## DC ELECTICAL CHARACTERISTICS

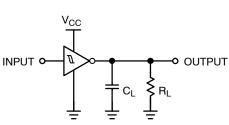
					T <sub>A</sub> = +25°C		T <sub>A</sub> = -40	to +85°C	
Symbol	Parameter	V <sub>CC</sub> (V)	Conditions	Min	Тур	Max	Min	Max	Unit
$V_P$	Positive Threshold Voltage	1.65		-	1.10	1.50	_	1.50	V
		2.30		-	1.40	1.80	_	1.80	
		3.00		-	1.75	2.20	_	2.20	
		4.50		-	2.45	3.10	_	3.10	
		5.50		-	2.90	3.60	_	3.60	
V <sub>N</sub>	Negative Threshold Voltage	1.65		0.25	0.55	-	0.25	-	V
		2.30		0.40	0.75	-	0.40	-	
		3.00		0.60	1.00	-	0.60	-	
		4.50		1.00	1.43	-	1.00	-	
		5.50		1.20	1.70	-	1.20	-	
V <sub>H</sub>	Hysteresis Voltage	1.65		0.15	0.54	1.00	0.15	1.00	V
		2.30		0.25	0.65	1.10	0.25	1.10	
		3.00		0.40	0.77	1.20	0.40	1.20	
		4.50		0.60	1.01	1.50	0.60	1.50	1
		5.50		0.70	1.18	1.70	0.70	1.70	
V <sub>OH</sub>	HIGH Level Output Voltage	1.65	$V_{IN} = V_P \text{ or } V_N$	1.55	1.65	-	1.55	-	V
		2.30	I <sub>OH</sub> = -100 μA	2.20	2.30	-	2.20	-	
		3.00		2.90	3.00	-	2.90	-	
		4.50		4.40	4.50	-	4.4	-	
		1.65	I <sub>OH</sub> = -4 mA	1.29	1.52	-	1.29	-	
		2.30	I <sub>OH</sub> = -8 mA	1.90	2.15	-	1.90	-	
		3.00	I <sub>OH</sub> = -16 mA	2.40	2.80	-	2.40	-	
		3.00	I <sub>OH</sub> = -24 mA	2.30	2.68	-	2.30	-	
		4.50	I <sub>OH</sub> = -32 mA	3.80	4.20	-	3.80	-	
V <sub>OL</sub>	LOW Level Output Voltage	1.65	$V_{IN} = V_P \text{ or } V_N,$	-	0.00	0.10	_	0.10	V
		2.30	l <sub>OL</sub> = 100 μA	-	0.00	0.10	_	0.10	
		3.00		-	0.00	0.10	-	0.10	
		4.50		-	0.00	0.10	-	0.10	
		1.65	I <sub>OL</sub> = 4 mA	-	0.08	0.24	_	0.24	
		2.30	I <sub>OL</sub> = 8 mA	-	0.10	0.30	_	0.30	
		3.00	I <sub>OL</sub> = 16 mA	-	0.15	0.40	_	0.40	1
		3.00	I <sub>OL</sub> = 24 mA	-	0.22	0.55	_	0.55	1
		4.50	I <sub>OL</sub> = 32 mA	-	0.22	0.55	_	0.55	1
I <sub>IN</sub>	Input Leakage Current	1.65 to 5.5	V <sub>IN</sub> = 5.5 V, GND	-	-	±0.1	-	±1.0	μΑ
I <sub>OFF</sub>	Power Off Leakage Current	0	V <sub>IN</sub> or V <sub>OUT</sub> = 5.5 V	-	-	1	_	10	μΑ
I <sub>CC</sub>	Quiescent Supply Current	1.65 to 5.50	V <sub>IN</sub> = 5.5 V, GND	-	_	1.0	_	10	μΑ



#### **AC ELECTRICAL CHARACTERISTICS**

				T <sub>A</sub> = +25°C			T <sub>A</sub> = -40	to +85°C	
Symbol	Parameter	V <sub>CC</sub> (V)	Conditions	Min	Тур	Max	Min	Max	Unit
t <sub>PLH</sub> , t <sub>PHL</sub>	Propagation Delay	1.80 ±0.15		-	7.6	12.5	-	13.0	ns
	(Figure 5, 6)	2.50 ±0.20	$R_L = 1 M\Omega$ ,	-	5.0	9.0	-	9.5	
		3.30 ±0.30		=	3.7	6.3	-	6.5	
		5.00 ±0.50		=	3.1	5.2	-	5.5	
		3.30 ±0.30	$C_L = 50 \text{ pF},$ $R_L = 500 \Omega,$	_	4.4	7.2	-	7.5	
		5.00 ±0.50	nL = 500 \$2,	-	3.7	5.9	-	6.2	
C <sub>IN</sub>	Input Capacitance	0.00		-	2.5	-	-	-	pF
C <sub>PD</sub>	C <sub>PD</sub> Power Dissipation Capacitance (Note 4) (Figure 7)	3.30		=	9	-	_	-	pF
		5.00		_	11	-	-	-	

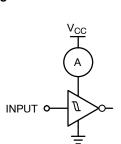
<sup>4.</sup> C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I<sub>CCD</sub>) at no output loading and operating at 50% duty cycle. C<sub>PD</sub> is related to I<sub>CCD</sub> dynamic operating current by the expression:
I<sub>CCD</sub> = (C<sub>PD</sub>) (V<sub>CC</sub>) (f<sub>IN</sub>) + (I<sub>CC</sub>static).



NOTE:

 C<sub>L</sub> includes load and stray capacitance; Input PRR = 1.0 MHz, t<sub>W</sub> = 500 ns.

Figure 5. AC Test Circuit



### NOTE:

6. Input = AC Waveform;  $t_r$  =  $t_f$  = 1.8 ns; PRR = 10 MHz; Duty Cycle = 50%.

Figure 7.  $I_{CCD}$  Test Circuit

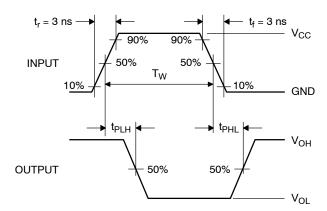


Figure 6. AC Waveforms

#### **ORDERING INFORMATION**

Part Number	Top Mark	Package	Shipping <sup>†</sup>
NC7NZ14K8X	NZ14	8-Lead US8, JEDEC MO-187, Variation CA 3.1 mm Wide	3000 / Tape & Reel
NC7NZ14L8X	P6	8-Lead MicroPak, 1.6 mm Wide	5000 / Tape & Reel

## **DISCONTINUED** (Note 7)

NC7NZ14L8X-L22185	P6	8-Lead MicroPak, 1.6 mm Wide	5000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

7. **DISCONTINUED:** This device is not recommended for new design. Please contact your **onsemi** representative for information. The most

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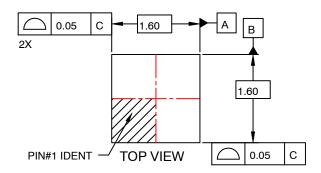


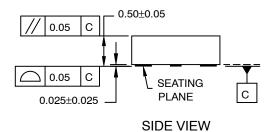
current information on this device may be available on www.onsemi.com.

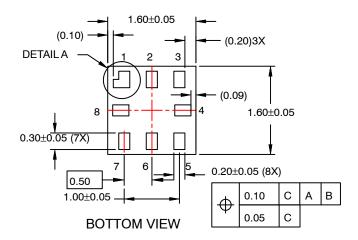


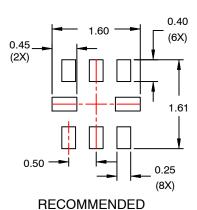
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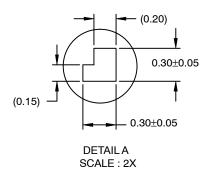


## NOTES:

- A. PACKAGE CONFORMS TO JEDEC MO-255 VARIATION UAAD.
- B. DIMENSIONS ARE IN MILLIMETERS.

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- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 2009.
- D. LAND PATTERN RECOMMENDATION IS EXISTING INDUSTRY LAND PATTERN.



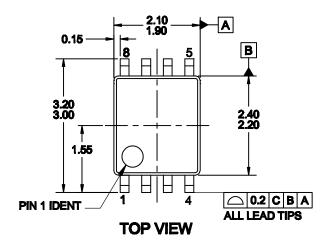
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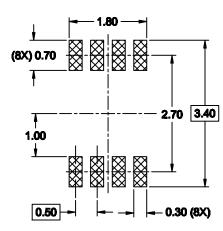
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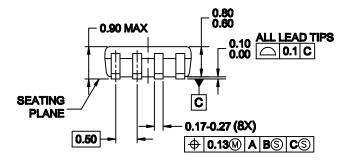
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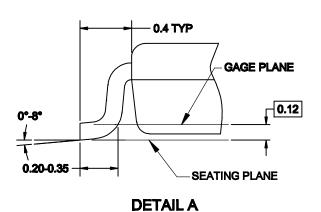
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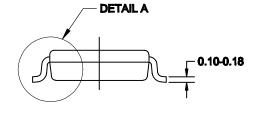


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- C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
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## SIDE VIEW





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